

INTERNATIONAL RECTIFIER

1N3879, 1N3889, 6FL, 12FL, 16FL SERIES

6A, 12A and 16A Fast Recovery Rectifiers

Major Ratings and Characteristics

	1N3879 —1N3883	1N3889 —1N3893	6FL...	12FL...	16FL...	Unit	
$I_F(AV)^{\dagger}$	6*	12*	6	12	16	A	
I_{FSM}	50Hz	72	145	110	145	180	A
	60Hz	75*	150*	115	150	190	A
I^2t	50Hz	26	103	60	103	160	A ² s
	60Hz	23	94	55	94	150	A ² s
$I_A\sqrt{t}$	363	1452	855	1452	2290	A \sqrt{s}	
t_{rr} range	see table					ns	
V_{RRM} range	50 — 400*		50 — 1000			V	
T_J range	—65 to 150					°C	

*JEDEC registered values.

† At max. $T_C = 100^\circ\text{C}$.

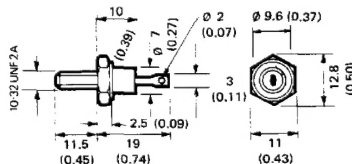
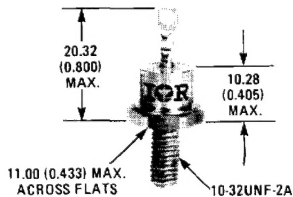
Description

This range of fast recovery diodes is designed for applications in DC power supplies, inverters, converters, choppers, ultrasonic systems and for use as free wheel diodes.

Features

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Standard JEDEC types
- Stud cathode and stud anode versions
- Types up to 1000V V_{RRM}
- Fully characterised reverse recovery conditions

CASE STYLE AND DIMENSIONS



Conforms to JEDEC: DO-203AA (DO-4)
IEC 191-2: A3U
BS 3934: SO-10A
DIN 41885: 101 C 2

All dimensions in millimetres (inches)

REVERSE VOLTAGE RATINGS

Part Number ① ②			VRRM – Max. Repetitive Peak Reverse Voltage	VRRM – Max. Non-Repetitive Peak Reverse Voltage $t_p \leq 5 \text{ ms}$	IR – Max. Reverse Current At Rated V_R		
			V	V	$T_J = 25^\circ\text{C}$	$T_J = 100^\circ\text{C}$	$T_J = 150^\circ\text{C}$
					μA	mA	mA
	1N3879		50	75	0.015*	1.0*	3.0*
	1N3880		100	150	0.015*	1.0*	3.0*
	1N3881		200	250	0.015*	1.0*	3.0*
	1N3882		300	350	0.015*	1.0*	3.0*
	1N3883		400	450	0.015*	1.0*	3.0*
	1N3889		50	75	0.025*	3.0*	5.0*
	1N3890		100	150	0.025*	3.0*	5.0*
	1N3891		200	250	0.025*	3.0*	5.0*
	1N3892		300	350	0.025*	3.0*	5.0*
	1N3893		400	450	0.025*	3.0*	5.0*
**6FL6S02	6FL6S05	6FL6S10	50	75	0.050	—	6.0
6FL10S02	6FL10S05	6FL10S10	100	150	0.050	—	6.0
6FL20S02	6FL20S05	6FL20S10	200	275	0.050	—	6.0
6FL40S02	6FL40S05	6FL40S10	400	500	0.050	—	6.0
6FL60S02	6FL60S05	6FL60S10	600	725	0.050	—	6.0
—	6FL80S05	6FL80S10	800	950	0.050	—	6.0
—	6FL100S05	6FL100S10	1000	1250	0.050	—	6.0
**12FL5S02	12FL5S05	12FL5S10	50	75	0.050	—	6.0
12FL10S02	12FL10S05	12FL10S10	100	150	0.050	—	6.0
12FL20S02	12FL20S05	12FL20S10	200	275	0.050	—	6.0
12FL40S02	12FL40S05	12FL40S10	400	500	0.050	—	6.0
12FL60S02	12FL60S05	12FL60S10	600	725	0.050	—	6.0
—	12FL80S05	12FL80S10	800	950	0.050	—	6.0
—	12FL100S05	12FL100S10	1000	1250	0.050	—	6.0
**16FL5S02	16FL5S05	16FL5S10	50	75	0.050	—	6.0
16FL10S02	16FL10S05	16FL10S10	100	150	0.050	—	6.0
16FL20S02	16FL20S05	16FL20S10	200	275	0.050	—	6.0
16FL40S02	16FL40S05	16FL40S10	400	500	0.050	—	6.0
16FL60S02	16FL60S05	16FL60S10	600	725	0.050	—	6.0
—	16FL80S05	16FL80S10	800	950	0.050	—	6.0
—	16FL100S05	16FL100S10	1000	1250	0.050	—	6.0

REVERSE RECOVERY CHARACTERISTICS

	1N3879– 1N3883	1N3889– 1N3893	6FL...			12FL...			16FL...			Unit	Conditions
			S02	S05	S10	S02	S05	S10	S02	S05	S10		
t_{rr} Max. reverse recovery time	150	150	110	285	490	100	250	430	90	225	390	ns	$T_J = 25^\circ\text{C}$, $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $dI_F/dt = 100\text{ A}/\mu\text{s}$
	300*	300*	200	500	1000	200	500	1000	200	500	1000	ns	$T_J = 25^\circ\text{C}$, $dI_F/dt = 25\text{ A}/\mu\text{s}$
$I_{RM}(\text{REC})$ Max. peak reverse recovery current	4*	5*	—	—	—	—	—	—	—	—	—	—	$I_{FM} = \pi \times \text{rated } I_F(\text{AV})$
Q_{RR} Max. reverse recovered charge	400	350	230	1700	5000	200	1300	3800	150	1100	3000	nC	$T_J = 25^\circ\text{C}$, $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $dI_F/dt = 100\text{ A}/\mu\text{s}$
	400	400	200	1200	5000	200	1200	5000	200	1200	5000	nC	$T_J = 25^\circ\text{C}$, $dI_F/dt = 25\text{ A}/\mu\text{s}$ $I_{FM} = \pi \times \text{rated } I_F(\text{AV})$

ELECTRICAL SPECIFICATIONS

		1N3879— 1N3883	6FL...	1N3889— 1N3893	12FL...	16FL...	Unit	Conditions	
FORWARD CONDUCTION									
$I_F(\text{AV})$	Max. average forward current	6*	6	12*	16	A	180° conduction, half sine wave, $T_C = 100^\circ\text{C}$		
$I_F(\text{RMS})$	Max. r.m.s. forward current	9.5	9.5	19	25	A			
I_{FSM}	Max. peak one-cycle non-repetitive forward current	72	110	145	180	A	$t = 10\text{ ms}$	With rated V_{RRM}	Sinusoidal half wave, initial $T_J = 150^\circ\text{C}$
		75*	115	150*	190		$t = 8.3\text{ ms}$		
		85	130	170	215		$t = 10\text{ ms}$		
		90	135	180	225		$t = 8.3\text{ ms}$		
i^2_t	Max. i^2_t for fusing	26	60	103	160	A^2s	$t = 10\text{ ms}$	With rated V_{RRM}	Initial $T_J = 150^\circ\text{C}$
		23	55	94	150		$t = 8.3\text{ ms}$		
	Max. i^2_t for individual device fusing	36	86	145	230		$t = 10\text{ ms}$		
		33	78	130	210		$t = 8.3\text{ ms}$		
$i^2 \sqrt{t}$	Max. $i^2 \sqrt{t}$ for individual device fusing ①	363	856	1452	2290	$i^2 \sqrt{t}$	$t = 0.1$ to 10 ms		
V_{FM}	Max. peak forward voltage	1.4*	1.4	1.4*	1.4	V	$T_J = 25^\circ\text{C}$, $I_F = \text{rated } I_F(\text{AV})$ (D.C.)		
		1.5*	1.5	1.5*	1.5		$T_C = 100^\circ\text{C}$, $I_{FM} = \pi \times \text{rated } I_F(\text{AV})$		

* JEDEC registered value

** Suffix "S02" may be omitted, i.e., 12FL10 implies 12FL10S02, 12FLR60 implies 12FLR60S02.

① Types listed are cathode to case; for anode-to-case include "R" in code, i.e., 1N3879R, 6FLR20S10, 16FLR40S02.

① $I_R(\text{AV})$ @ rated $I_F(\text{AV})$ and V_{RRM} , and $T_C = 100^\circ\text{C}$.② I_{RM} @ rated V_{RRM} and $T_J = 150^\circ\text{C}$.③ i^2_t for time $t_x = i^2 \sqrt{t} \times \sqrt{x}$

④ When these devices are ordered without a suffix, e.g., 40HFL, the order will be filled with devices that meet the S02 specification.

Thermal and mechanical specifications

				1N3879 -1N3883 6FL...	1N3889 -1N3893 12FL...	16FL...	Units	Conditions
T_J	Junction operating temperature range			-65 to 150			$^{\circ}\text{C}$	
T_{stg}	Storage temperature range			-65 to 175			$^{\circ}\text{C}$	
R_{thJC}	Maximum internal thermal resistance, junction to case			2.5	2.0	1.6	deg C/W	DC operation
R_{thCS}	Maximum thermal resistance, case to heatsink			0.5			deg C/W	Mounting surface flat, smooth and greased.
T	Mounting torque $\pm 10\%$	to nut	10.5			lb \cdot in	Lubricated threads (Non-lubricated threads)	
			0.12			kgf \cdot m		
			1.2			Nm		
	to device	11.5 (13.5)			lb \cdot in			
		0.13 (0.155)			kgf \cdot m			
		1.3 (1.35)			Nm			
wt	Approximate weight	7			g			
		0.25			oz			
		Case style			DO-203AA (DO-4)		JEDEC	

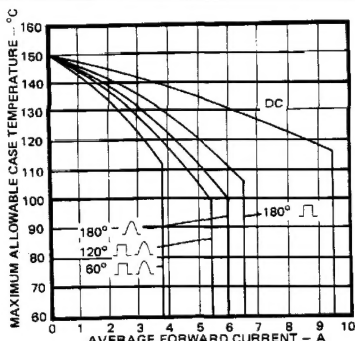


Fig. 1 - Average Forward Current Vs. Maximum Allowable Case Temperature, 1N3879 and 6FL Series

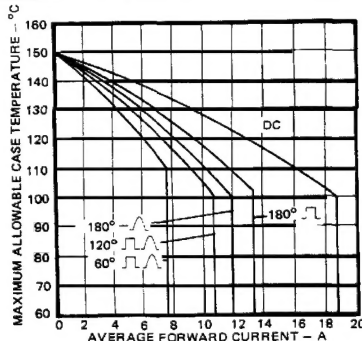


Fig. 2 - Average Forward Current Vs. Maximum Allowable Case Temperature, 1N3889 and 12FL Series

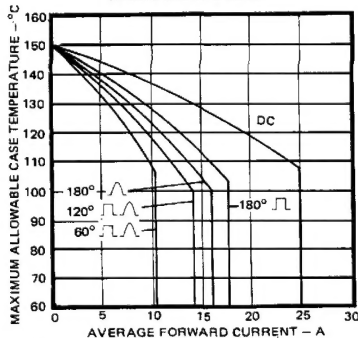
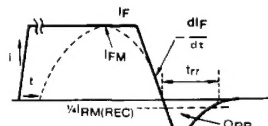
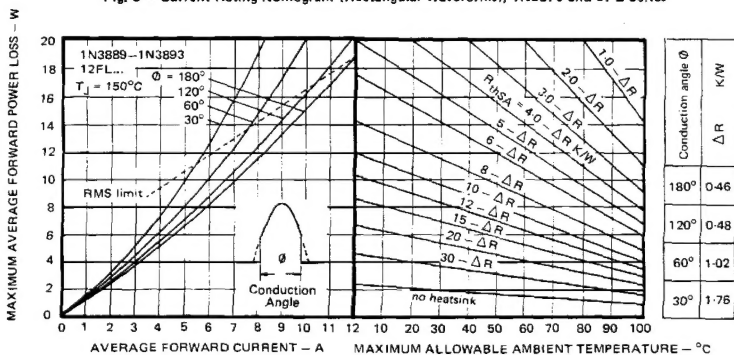
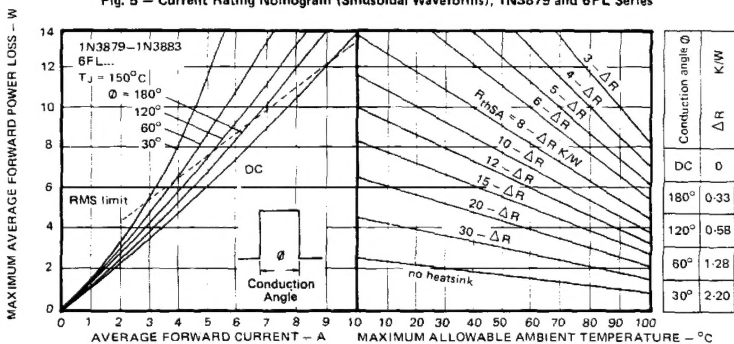
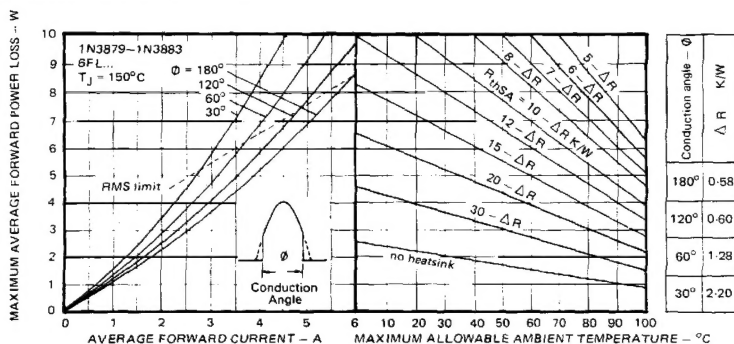


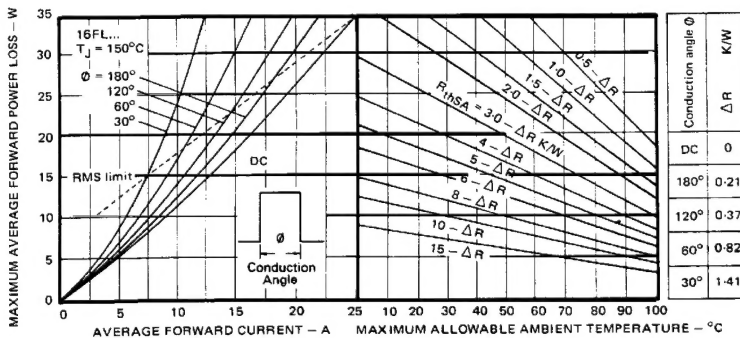
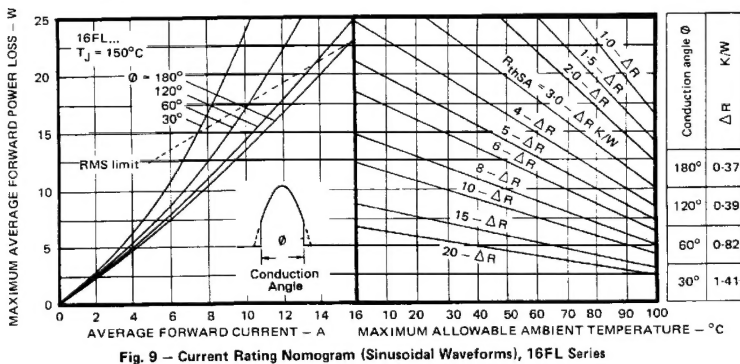
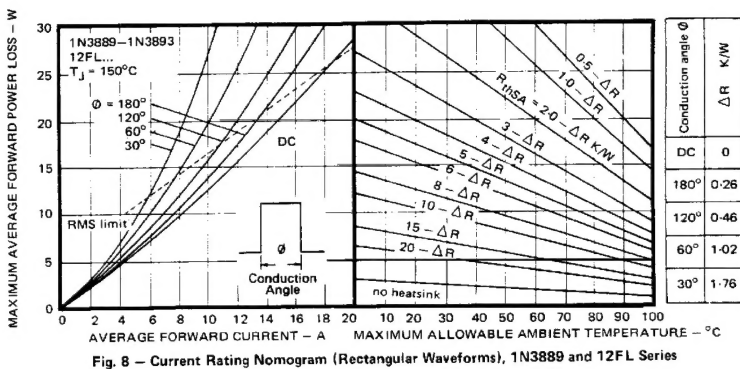
Fig. 3 - Average Forward Current Vs. Maximum Allowable Case Temperature, 16FL Series



- I_F, I_{FM} = Peak forward current prior to commutation
 $-dI_F/dt$ = Rate of fall of forward current
 $I_{RM}(REC)$ = Peak reverse recovery current
 t_{rr} = Reverse recovery time
 Q_{RR} = Reverse recovered charge

Fig. 4 - Reverse Recovery Time Test Waveform





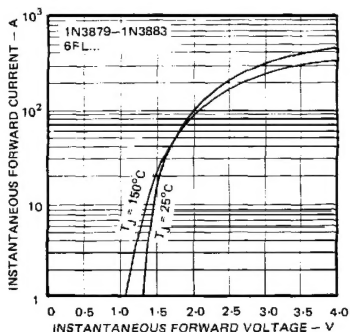


Fig. 11 - Maximum Forward Voltage Vs. Forward Current, 1N3879 and 6FL Series

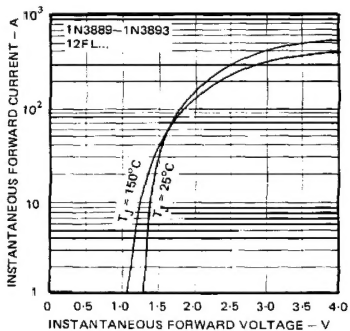


Fig. 13 - Maximum Forward Voltage Vs. Forward Current, 1N3889 and 12FL Series

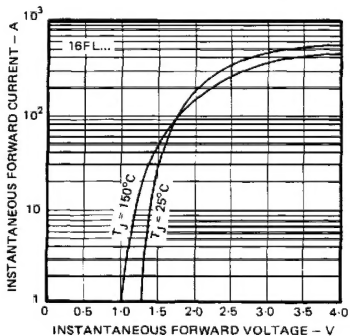


Fig. 15 - Maximum Forward Voltage Vs. Forward Current, 16FL Series

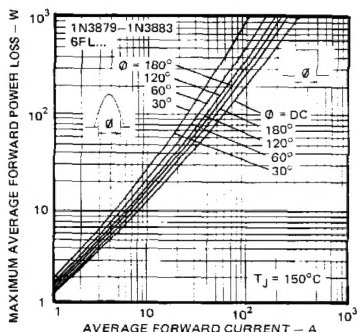


Fig. 12 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 1N3879 and 6FL Series

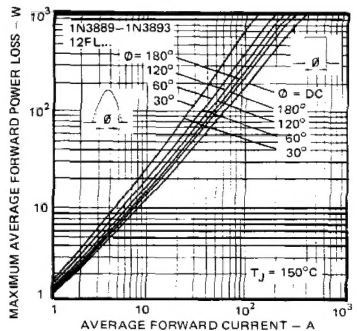


Fig. 14 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 1N3889 and 12FL Series

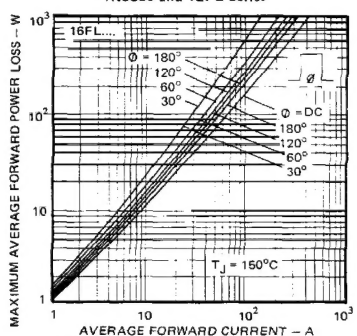


Fig. 16 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 16FL Series

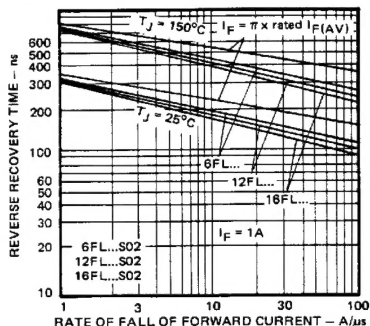


Fig. 17A - Maximum Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S02

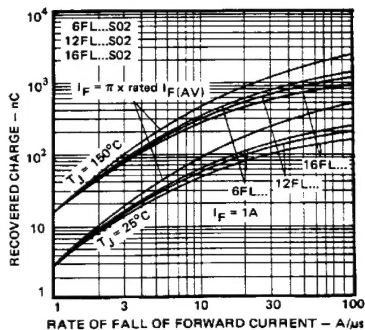


Fig. 17B - Maximum Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S02

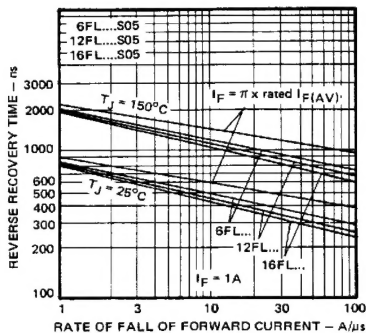


Fig. 18A - Maximum Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S05

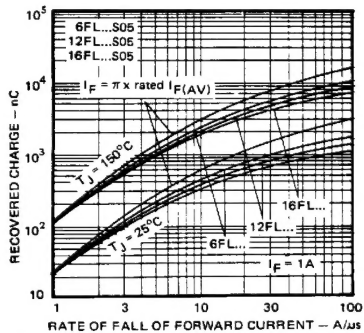


Fig. 18B - Maximum Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S05

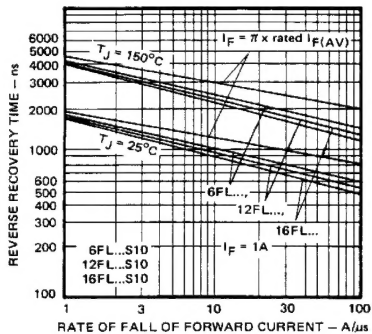


Fig. 19A - Maximum Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S10

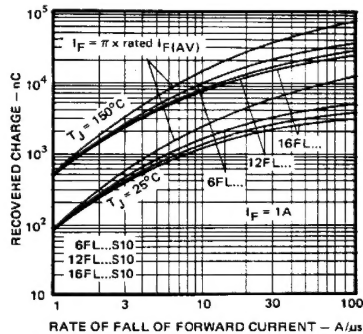


Fig. 19B - Maximum Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S10

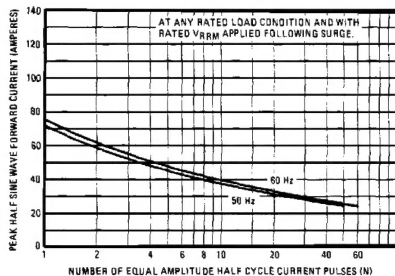


Fig. 20 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 1N3879 Series

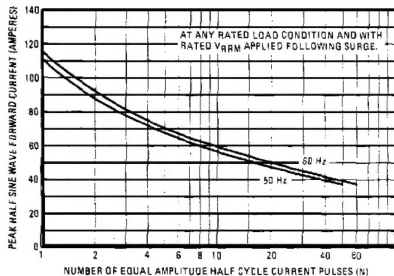


Fig. 21 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 6FL Series

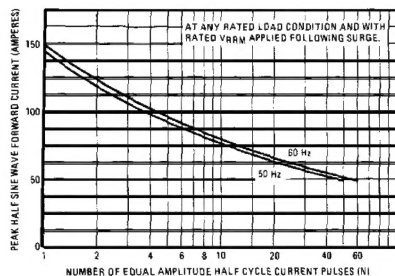


Fig. 22 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 1N3889 and 12FL Series

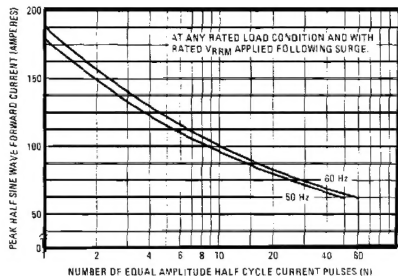


Fig. 23 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 16FL Series

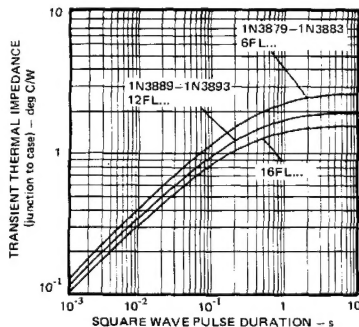


Fig. 24 - Maximum Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration, All Series.